

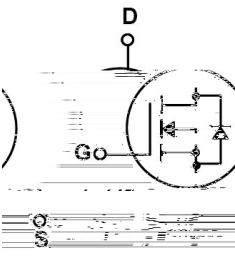
[illegible]



TO-252                    N  
N-CHANNEL MOSFET in a TO-252 Plastic Package.

$R_{DS(on)}$                      $C_{rss}$   
Low  $R_{DS(on)}$ , low gate charge, low  $C_{rss}$ , fast switching, HF Product.

DC/DC  
Suited for low voltage applications such as automotive, DC/DC Converters, and high efficiency switching for power management in portable and battery operated products.



PIN1   G                    PIN 2   D                    PIN 3   S                    PIN 4   D

See Marking Instructions.

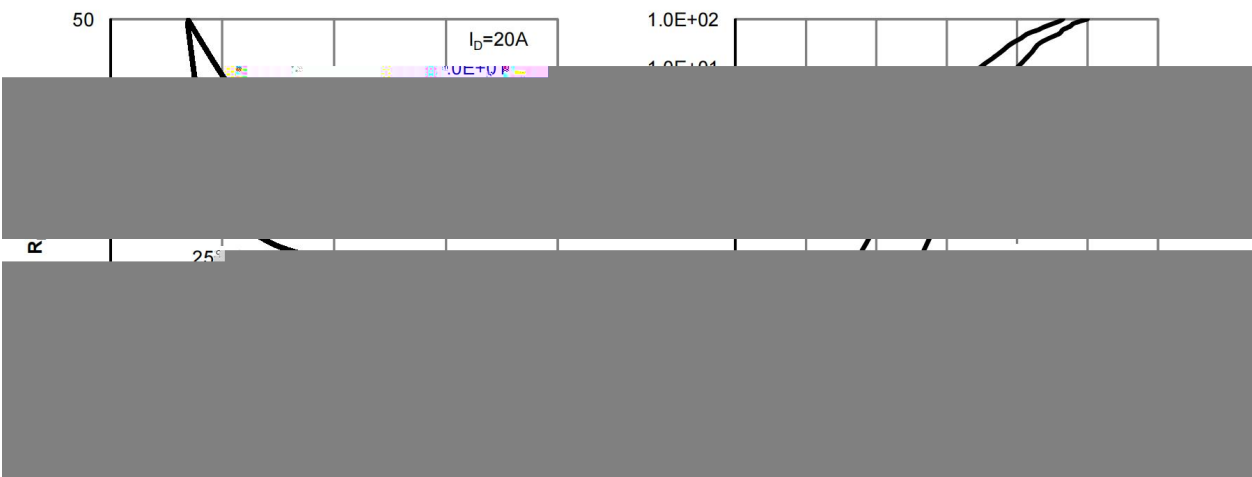
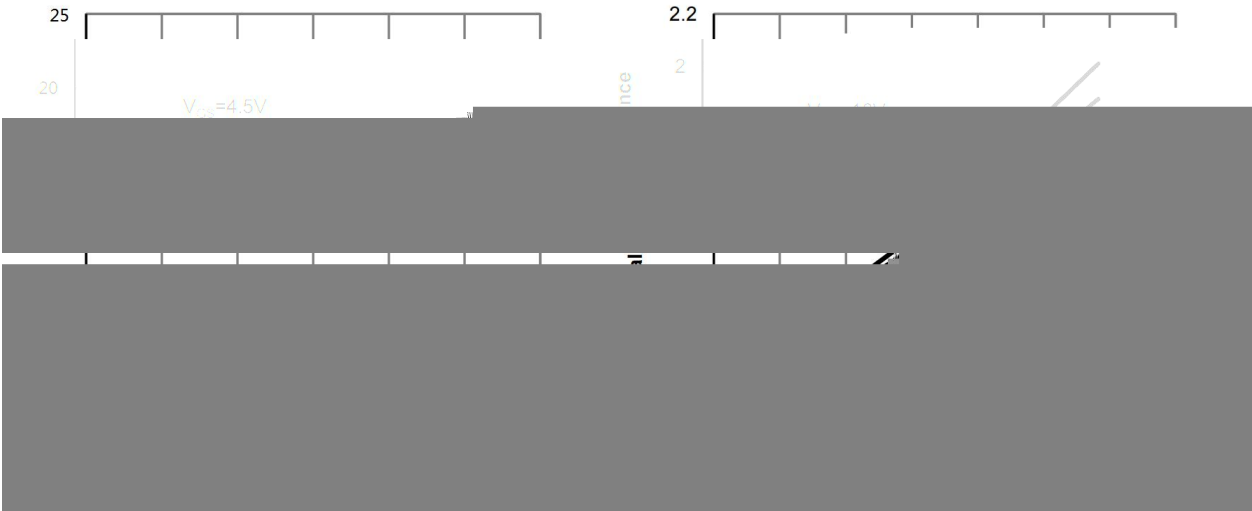


| Parameter                               |                     | Symbol                      | Rating     | Unit               |
|-----------------------------------------|---------------------|-----------------------------|------------|--------------------|
| Drain-Source Voltage                    |                     | $V_{DSS}$                   | 100        | V                  |
| Drain Current                           |                     | $I_D(T_c=25^\circ\text{C})$ | 55         | A                  |
| Drain Current - Pulsed                  |                     | $I_{DM}$                    | 138        | A                  |
| Gate-Source Voltage                     |                     | $V_{GS}$                    | $\pm 20$   | V                  |
| Avalanche Current                       |                     | $I_{AS}$                    | 7.0        | A                  |
| Single Pulsed Avalanche Energy(L=0.5mH) |                     | $E_{AS}$                    | 24.5       | mJ                 |
| Power Dissipation                       |                     | $P_D(T_c=25^\circ\text{C})$ | 73         | W                  |
| Storage Temperature Range               |                     | $T_{stg}$                   | -55 to 150 | $^\circ\text{C}$   |
| Thermal Resistance-Junction to Ambient  | $t \leq 10\text{s}$ | $R_{\theta JA}$             | 20         | $^\circ\text{C/W}$ |
|                                         | Steady-State        |                             | 50         |                    |
| Thermal Resistance-Junction to Case     | Steady-State        | $R_{\theta JC}$             | 1.7        |                    |

| Parameter                         | Symbol       | Test Conditions                | Min | Typ | Max       | Unit    |
|-----------------------------------|--------------|--------------------------------|-----|-----|-----------|---------|
| Drain-Source Breakdown Voltage    | $BV_{DSS}$   | $V_{GS}=0V$ $I_D=250\mu A$     | 100 | 108 |           | V       |
| Zero Gate Voltage Drain Current   | $I_{DSS}$    | $V_{DS}=100V$ $V_{GS}=0V$      |     |     | 1.0       | $\mu A$ |
| Gate-Body Leakage Current Forward | $I_{GSS}$    | $V_{GS}=20V$ $V_{DS}=0V$       |     |     | $\pm 100$ | nA      |
| Gate Threshold Voltage            | $V_{GS(th)}$ | $V_{DS}=V_{GS}$ $I_D=250\mu A$ | 1.5 | 1.8 | 2.5       | V       |

Static Drain-Source  
On-

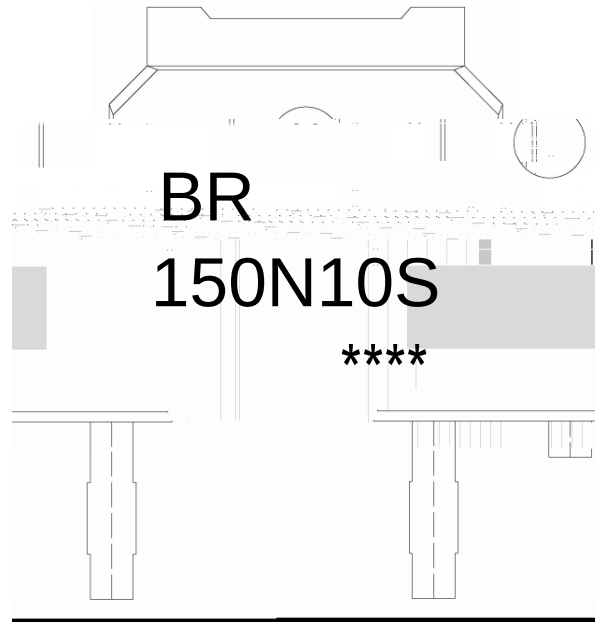






Rev.A Feb.-2022

<http://>



BR

150N10S

\*\*\*\*

Note:

BR: Company Code

150N10S: Product Type Code

\*\*\*\*: Lot No. Code, code change with Lot No



|  |
|--|
|  |
|  |
|  |
|  |
|  |
|  |
|  |

## Note:

- |   |           |             |                                         |
|---|-----------|-------------|-----------------------------------------|
| 1 | 150 ~ 180 | 60 ~ 90sec; | 1.Preheating:150~180 , Time:60~90sec.   |
| 2 | 245±5     | 5±0.5sec;   | 2.Peak Temp.:245±5 , Duration:5±0.5sec. |
| 3 | 2 ~ 10    | /sec.       | 3. Cooling Speed: 2~10 /sec.            |

260±5

10±1 sec.

Temp.:260±5℃

Time:10±1 sec

/ REEL

Package Type

Units

Dimension

(unit mm)